



, INC.

## 27CX256

### 256K (32K x 8) CMOS High-Speed EPROM

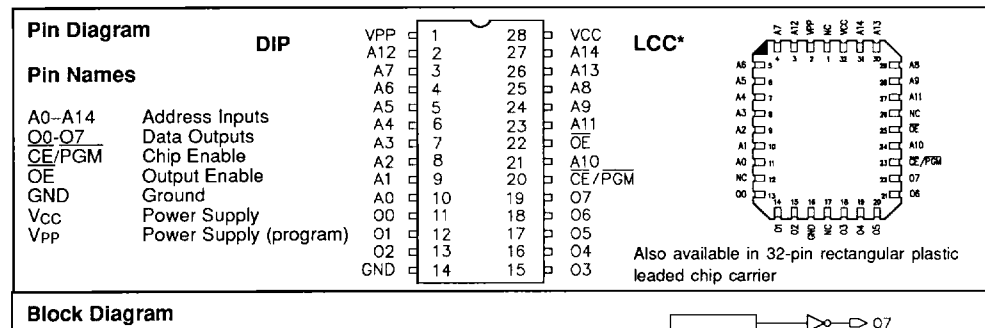
#### Features

- **Advanced CMOS EPROM Technology**
- **High Performance / Industry's Fastest**
  - 27CX256-35  $t_{AA} = 35\text{ns max}$
  - 27CX256-45  $t_{AA} = 45\text{ns max}$
  - 27CX256-55  $t_{AA} = 55\text{ns max}$
- **Low Power Consumption**
  - 50mA Max Active
  - 25mA Max Standby, TTL interface
- **TTL-Compatible I/O**
- **Reprogrammability**
  - Adds convenience, reduces costs
  - Windowed package for UV erasure
  - Allows 100% factory testing
- **Programming Support**
  - Supported by popular programmers
  - Fast programming algorithm
  - Auto Select mode feature
- **Packaging**
  - JEDEC-standard 28-pin Ceramic

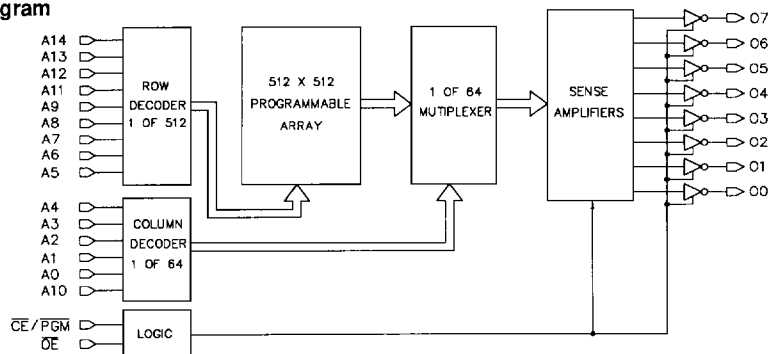
#### General Description

The ICT 27CX256 is a 262,144-bit CMOS high-speed UV-Erasable Programmable Read Only Memory, organized as 32K-bytes of 8 bits each. Available in a JEDEC-standard 28-pin package, the 27CX256 allows pin-compatible upgrades from 32K through 128K-bit EPROMS with minimal or no hardware changes. The 27CX256 is designed using an advanced CMOS EPROM technology which provides ultra-fast access times (35, 45, 55ns max) and a low active power consumption (50mA max). The high-speed of the 27CX256 makes it ideal for operation with fast 16-bit and 32-bit microproces-

sors, eliminating the necessity of wait states. The 27CX256's high density allows the storage of operating systems and applications software, freeing the system's RAM for other uses. Popular third party vendor EPROM programmers will support the 27CX256 programming. An Auto Select mode provides for foolproof programmer operation by allowing EPROM programmers to read a special code from the 27CX256 to identify manufacturer and part type.



#### Block Diagram



## Functional Description

### Erasure Characteristics

The 27CX256 is erased by exposure to an ultraviolet light source. For complete erasure, the recommended minimum integrated dose (UV intensity X exposure time) is 15 Watt-second/cm<sup>2</sup> of ultraviolet light with a wavelength of 2537 Å. For an ultraviolet lamp with a 12mW/cm<sup>2</sup> power rating, the exposure time should be approximately 20 minutes, with the device placed within one inch of the lamp during erasure. Exposing the CMOS EPROM to high-intensity UV light for extended periods may affect device reliability. Also, exposure to fluorescent light or sunlight may erase the EPROM. Therefore, an opaque label or substance should be placed over the package window if the device is used in such an environment.

### Programming Mode

After erasure, all bits of the EPROM are set to 1's. Programming of the 27CX256 stores 0's in the selected bit positions. The program mode is entered when a voltage between 12.5V and 13.0V is applied to the VPP pin, while CE/ PGM is held low and OE is high. Programming support is available from third-party manufacturers. For more information on programming support and programming specifications, please contact ICT.

### Read Mode

The 27CX256 has two control functions, Chip Enable (CE) and Output Enable (OE), which must both be held low for data to be accessed from the EPROM. CE is the power control and should be used for device selection. OE is the output control and should be used to gate data to the output pins if the device is selected.

It is recommended that CE be decoded and used as the primary device selecting function, while OE should be made a common connection to all devices in the array and connected to the read line from the system control bus. This will assure that all deselected memory devices are in their low-power standby mode and that the output pins are only active when data is desired from a particular device.

Assuming the addresses are stable, address access time ( $t_{ACC}$ ) is equal to the delay from CE to the output ( $t_{CS}$ ). Data is available at the outputs  $t_{OE}$  after the falling edge of OE, assuming CE has been low and addresses have been stable for at least  $t_{ACC-t_{OE}}$ .

### Standby Mode

The 27CX256 has a standby mode, during which current ( $I_{CC1}$ ) is less than 25mA, and the outputs 00-QZ are in the high impedance state, independent of OE input.

### Auto Select Mode

The Auto Select Mode allows the reading out of a two-byte binary code from the EPROM that will identify its manufacturer and part type. This mode is intended for use by programming equipment for the purpose of automatically matching the device being programmed with its corresponding programming algorithm. The two codes identified are the Manufacturer code and the Device code. These codes are given in the Mode table. All identifiers for manufacturers and devices will exhibit odd parity with the MSB (O7) defined as the parity bit.

### Program Inhibit Mode

Multiple 27CX256 devices can be programmed in parallel by wiring all like inputs of the EPROMs except for CE. Different data can also be programmed into each EPROM while in parallel. Devices with CE and OE held HIGH are inhibited from being programmed. The chosen device can then be programmed by setting CE to a LOW TTL level and applying 12.5V to VPP. (See mode table)

### Program Verify Mode

A verify should be performed on the programmed bits of the 27CX256 to determine the correct programming of the EPROM.

This is accomplished by taking CE to  $V_{IH}$  and OE to  $V_{IL}$ , and applying 12.5V to VPP.

**Absolute Maximum Ratings**

Exposure to absolute maximum ratings over extended periods of time may affect device reliability. Exceeding absolute maximum ratings may cause permanent damage

Symbol	Parameter	Conditions	Rating	Unit
V <sub>CC</sub>	Supply Voltage	Relative to GND	- 0.6 to +7.0	V
V <sub>IO</sub>	Voltage Applied to All Pins Except A9, V <sub>PP</sub>	Relative to GND	-0.6 to V <sub>CC</sub> +0.6	V
V <sub>IO2</sub>	Voltage Applied to A9 and V <sub>PP</sub>	Relative to GND	-0.6 to +13.5	V
T <sub>A</sub>	Ambient Temp., Power Applied		-65 to +150	°C
T <sub>ST</sub>	Storage Temperature		-65 to +150	°C
T <sub>LT</sub>	Lead Temperature	Soldering 10 seconds	+ 300	°C

**Operating Ranges**

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>A</sub>	Ambient Temperature	Commercial/Industrial	0/-40	70/+85	°C
V <sub>CC</sub>	Supply Voltage (Read)	Commercial	4.5	5.5	V
V <sub>CCP</sub>	Supply Voltage (Program)	Commercial	6.0	6.5	V
V <sub>CCV</sub>	Supply Voltage (Verify)	Commercial	5.0	5.5	V
V <sub>PP</sub>	Program Voltage	Commercial	12.5	13.0	V

**D.C. Electrical Characteristics<sup>1,2</sup>**

Over the operating range

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>IH</sub>	Input HIGH Level		2.0	V <sub>CC</sub> +5	V
V <sub>IL</sub>	Input LOW Level		-0.3	0.8	V
V <sub>OH</sub>	Output HIGH Voltage <sup>3</sup>	V <sub>CC</sub> = Min, I <sub>OH</sub> = -4.0mA	2.4		V
V <sub>OL</sub>	Output LOW Voltage <sup>3</sup>	V <sub>CC</sub> = Min, I <sub>OL</sub> = 12mA		0.45	V
I <sub>LI</sub>	Input Leakage Current	V <sub>IN</sub> = 0V to V <sub>CC</sub>		10	μA
I <sub>LO</sub>	Output Leakage Current	V <sub>out</sub> = 0V to V <sub>CC</sub>		10	μA
I <sub>CC1</sub>	V <sub>CC</sub> Standby Current (TTL)	Commercial/Industrial /CE=V <sub>IH</sub> , /OE=V <sub>IL</sub>		25/35	mA
I <sub>CC2</sub>	V <sub>CC</sub> Active Current	Commercial/Industrial /CE=V <sub>IL</sub> , /OE=V <sub>IH</sub> , f=10MHz		50/60	mA
I <sub>PP1</sub>	V <sub>PP</sub> Current During Read	V <sub>PP</sub> = 5.5V		100	μA

**Capacitance**

These measurements are periodically sample tested.

Symbol	Parameter	Conditions	Min	Max	Unit
C <sub>IN</sub>	Input Capacitance	T <sub>A</sub> = 25°C V <sub>CC</sub> = 5.0V @ f = 1MHz		8	pF
C <sub>OUT</sub>	Output Capacitance			8	pF
C <sub>IN2</sub>	V <sub>PP</sub> Input Capacitance			20	pF

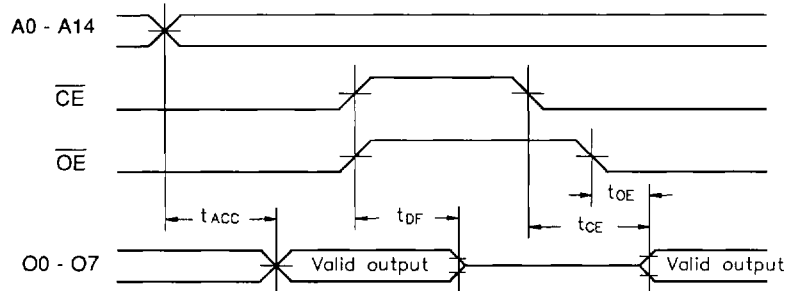
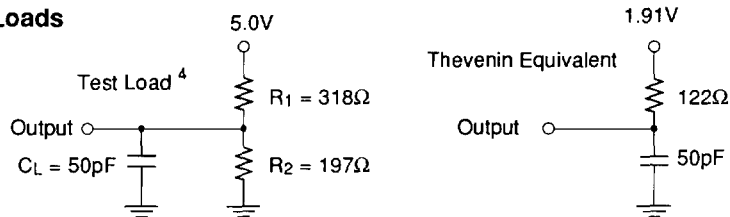
**Notes:**

- V<sub>CC</sub> must be applied simultaneously or before V<sub>PP</sub>, and removed simultaneously or after V<sub>PP</sub>.
- It is recommended that V<sub>PP</sub> be connected directly to V<sub>CC</sub> except during programming. The supply current will be I<sub>CC</sub> + I<sub>PP1</sub>.
- The 27CX256 provides true CMOS output interface levels. The specifications shown are for a TTL interface.

**A.C. Electrical Characteristics**

 Over the Operating Range <sup>4</sup>

Symbol	Parameter	27CX256-35		27CX256-45		27CX256-55		Unit
		Min	Max	Min	Max	Min	Max	
t <sub>ACC</sub>	Access Time From Address To Output		35		45		55	ns
t <sub>CE</sub>	Access Time From Chip Enable To Output		35		45		55	ns
t <sub>OE</sub>	Access Time From Output Enable To Output <sup>5</sup>		20		20		25	ns
t <sub>DF</sub>	Chip Disable to High-Z <sup>5,6</sup>		20		20		25	ns

**Switching Waveforms**

**Test Loads**

**Notes:**

4. Test conditions assume: signal transition times of 5 nS or less from the 10% and 90% points; timing reference levels of 1.5V (unless otherwise specified); and test loads shown.

5. t<sub>CE</sub> and t<sub>OE</sub> are measured from the input transition to V<sub>REF</sub> ± 0.1V. t<sub>DF</sub> is measured from the input transition to V<sub>OH</sub> - 0.1V or V<sub>OL</sub> + 0.1V.

6. C<sub>L</sub> includes scope and jig capacitance. t<sub>DF</sub> is tested with C<sub>L</sub> = 5pF

**Mode Table**

Mode		CE/PGM	OE	VPP	VCC	A9	A0	Output
Read		VIL	VIL	VCC	VCC	X	X	DOUT
Standby		VIH	X	VCC	VCC	X	X	HI-Z
Output Disable		VIL	VIH	VCC	VCC	X	X	HI-Z
Program		VIL	VIH	VPP	VCC	X	X	DIN
Program Verify		VIH	VIL	VPP	VCC	X	X	DOUT
Program Inhibit		VIH	VIH	VPP	VCC	X	X	HI-Z
Auto Select	Manufacturer	VIL	VIL	VCC	VCC	VH	VIL	01H
	Device	VIL	VIL	VCC	VCC	VH	VIH	10H

VIL = Input Low Voltage, VIH = Input High Voltage, VH = High Voltage (12.5V), X = VIL or VIH